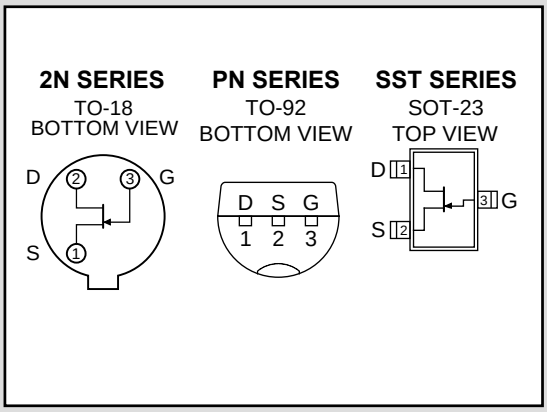
LINEAR SYSTEMS

Linear Integrated Systems

2N/PN/SST4391 SERIES

SINGLE N-CHANNEL JFET SWITCH

FEATURES	
Replacement for Siliconix 2N/PN/SST4391, 4292, & 4393	
LOW ON RESISTANCE	$r_{DS(on)} \leq 30\Omega$
FAST SWITCHING	$t_{ON} \leq 15ns$
ABSOLUTE MAXIMUM RATINGS[1] @ 25 °C (unless otherwise stated)	
Maximum Temperatures	
Storage Temperature (2N)	-65 to 200°C
Storage Temperature (PN/SST)	-55 to 150°C
Junction Operating Temperature (2N)	-55 to 200°C
Junction Operating Temperature (PN/SST)	-55 to 150°C
Maximum Power Dissipation	
Continuous Power Dissipation (2N)	1800mW
Continuous Power Dissipation (PN/SST)	350mW
Maximum Currents	
Gate Current	50mA
Maximum Voltages	
Gate to Drain or Source (2N/PN)	-40V
Gate to Drain or Source (SST)	-35V



STATIC ELECTRICAL CHARACTERISTICS @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS
				MIN	MAX	MIN	MAX	MIN	MAX		
BV_{GSS}	Gate to Source Breakdown Voltage	2N/PN		-40		-40		-40		V	I_G = -1µA, V_{DS} = 0V
		SST		-35		-35		-35			
$V_{GS(off)}$	Gate to Source Cutoff Voltage	2N/PN		-4	-10	-2	-5	-0.5	-3		V_{DS} = 20V, I_D = 1nA
		SST		-4	-10	-2	-5	-0.5	-3		V_{DS} = 15V, I_D = 10nA
$V_{GS(F)}$	Gate to Source Forward Voltage		0.7		1		1		1		I_G = 1mA, V_{DS} = 0V
$V_{DS(on)}$	Drain to Source On Voltage		0.25						0.4		V_{GS} = 0V, I_D = 3mA
			0.3				0.4				V_{GS} = 0V, I_D = 6mA
			0.35		0.4						V_{GS} = 0V, I_D = 12mA
I_{DSS}	Drain to Source Saturation Current[2]	2N		50	150	25	75	5	30	mA	V_{DS} = 20V, V_{GS} = 0V
		PN		50	100	25	100	5	60		
		SST		50		25		5			
I_{GSS}	Gate Leakage Current	2N/SST	-5		-100		-100		-100	pA	V_{GS} = -20V, V_{DS} = 0V
		PN	-5		-1000		-1000		-1000		
I_G	Gate Operating Current		-5								V_{DG} = 15V, I_D = 10mA

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STATIC ELECTRICAL CHARACTERISTICS CONT. @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS
				MIN	MAX	MIN	MAX	MIN	MAX		
$I_{D(off)}$	Drain Cutoff Current	2N	5						100	pA	V_{DS} = 20V, V_{GS} = -5V
			5				100				V_{DS} = 20V, V_{GS} = -7V
			5		100						V_{DS} = 20V, V_{GS} = -12V
		PN	5						1000		V_{DS} = 20V, V_{GS} = -5V
			5				1000				V_{DS} = 20V, V_{GS} = -7V
			5		1000						V_{DS} = 20V, V_{GS} = -12V
		SST	5		100		100		100		V_{DS} = 10V, V_{GS} = -10V
$r_{DS(on)}$	Drain to Source On Resistance				30		60		100	Ω	V_{GS} = 0V, I_D = 1mA

DYNAMIC ELECTRICAL CHARACTERISTICS @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS
				MIN	MAX	MIN	MAX	MIN	MAX		
g_{fs}	Forward Transconductance		6							mS	V_{DS} = 20V, I_D = 1mA
g_{os}	Output Conductance		25							µS	*f* = 1kHz
$r_{ds(on)}$	Drain to Source On Resistance				30		60		100	Ω	V_{GS} = 0V, I_D = 0A *f* = 1kHz
C_{iss}	Input Capacitance	2N	12		14		14		14	pF	V_{DS} = 20V, V_{GS} = 0V *f* = 1MHz
		PN	12		16		16		16		
		SST	13								
C_{rss}	Reverse Transfer Capacitance	2N	3.3						3.5		V_{DS} = 0V, V_{GS} = -5V *f* = 1MHz
		PN	3.5						5		
		SST	3.6								
		2N	3.2				3.5				V_{DS} = 0V, V_{GS} = -7V *f* = 1MHz
		PN	3.4				5				
		SST	3.5								
		2N	2.8		3.5						V_{DS} = 0V, V_{GS} = -12V *f* = 1MHz
		PN	3.0		5						
		SST	3.1								
e_n	Equivalent Input Noise Voltage		3							nV/√Hz	V_{DS} = 10V, I_D = 10mA *f* = 1kHz

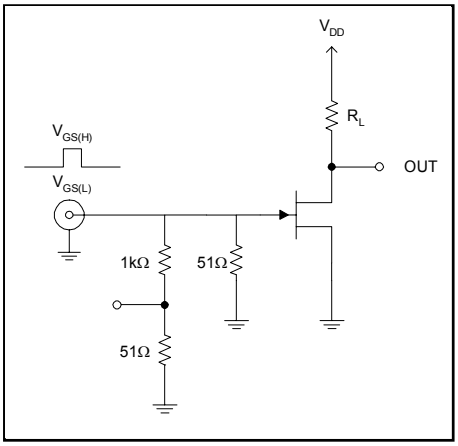
SWITCHING ELECTRICAL CHARACTERISTICS @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS
				MIN	MAX	MIN	MAX	MIN	MAX		
$t_{d(on)}$	Turn On Time	2N/PN	2		15		15		15	ns	V_{DD} = 10V, $V_{GS(H)}$ = 0V
		SST	2								
t_r		2N/PN	2		5		5		5		
		SST	2								
$t_{d(off)}$	Turn Off Time	2N/PN	6		20		35		50		
		SST	6								
t_f		2N/PN	13		15		20		30		
		SST	13								

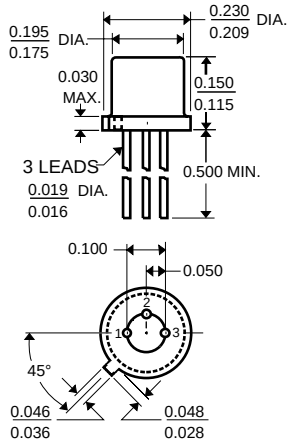
SWITCHING CIRCUIT CHARACTERISTICS

SYM.	4391	4392	4393
$V_{GS(L)}$	-12V	-7V	-5V
R_L	800Ω	1600Ω	3200Ω
$I_{D(on)}$	12mA	6mA	3mA

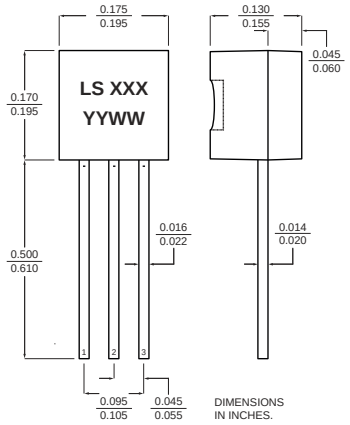
SWITCHING TEST CIRCUIT



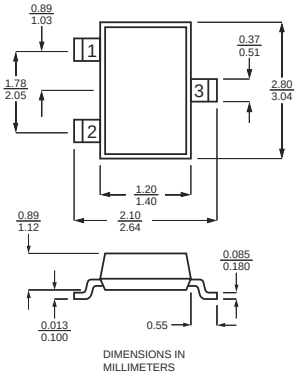
TO-18
Three Lead



TO-92



SOT-23



NOTES

1. Absolute maximum ratings are limiting values above which serviceability may be impaired.
2. Pulse test: PW ≤ 300μs, Duty Cycle ≤ 3%